



Low Voltage SPDT Analog Switch 2:1 Mux/Demux Bus Switch

Features

- CMOS Technology for Bus and Analog Applications
- Low On-Resistance: 8Ω at 3.0V
- Wide VCC Range: 1.65V to 5.5V
- Rail-to-Rail Signal Range
- Control Input Overvoltage Tolerance: 5.5V
- Fast Transition Speed: 2ns at 5.0V
- High Off Isolation: -63dB @ 10MHz
- Break-Before-Make Switching
- High Bandwidth: 350MHz
- Extended Industrial Temperature Range: -40°C to 85°C
- PI5A3157B Is Improved Direct Replacement for NC7SB3157
- Packaging (Pb-free & Green):
 - -6-pin UDFN 1mm×1mm
 - -6-pin SC70

Description

The PI5A3157B is a high-bandwidth, fast single-pole double-throw (SPDT) CMOS switch. It can be used as an analog switch or as a low-delay bus switch. Specified over a wide operating power supply voltage range, 1.65V to 5.5V, the PI5A3157B has a maximum ON resistance of 12-ohms at 1.65V, 9-ohms at 2.3V & 6-ohms at 4.5V.

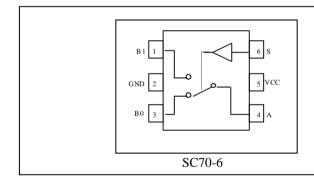
Break-before-make switching prevents both switches being enabled simultaneously. This eliminates signal disruption during switching.

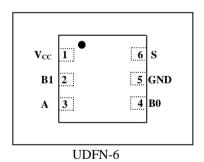
The control input, S, is independent of supply voltage. PI5A3157B is an improved direct replacement for the NC7SB3157.

Application

- Cell Phones
- PDAs
- MP3 Players
- Portable Instrumentation
- Battery powered Communications
- Computer Peripherals

Pin Assignment





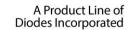
Pin Description

FIII Des								
Pin No		Pin Name	Decemention					
SC70-6	UDFN-6	riii Name	Description					
1	2	B1	Data Port					
2	5	GND	Ground					
3	4	В0	Data Port (Normally connected)					
4	3	A	Common Output/Data Port					
5	1	V _{CC}	Positive Power Supply					
6	6	S	Logic control					

Logic Function Table

Logic Inputs(S)	Function
0	B ₀ connect to A
1	B ₁ connect to A







Maximum Ratings

Storage Temperature	65°C to +150°C
Ambient Temperature with Power Applied	40°C to +85°C
Supply Voltage V _{CC}	0.5V to +7.0V
DC Control Input Voltage V _S	0.5V to +7.0V
DC Input Voltage V _{IN}	0.5V to V_{CC} +0.5V
DC Output Current V _{OUT}	128mA
DC V _{CC} or Ground Current I _{CC} /I _{GND}	±100mA
Junction Temperature under Bias (TJ)	150°C
Junction Lead Temperature (TL)	
(Soldering, 10 seconds)	260°C
Power Dissipation (PD) @ +85°C	180mW
ESD(HBM)	2000V

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Recommended Operating Conditions

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
V_{CC}	Operating Voltage	-	1.65	-	5.5	V
$V_{\rm S}$	Control Input Voltage	-	0	-	5.5	V
V _{IN}	Switch Input Voltage	-	0	-	V _{CC}	V
V _{OUT}	Output Voltage	-	0	-	V_{CC}	V
T_A	Operating Temperature	-	-40	25	85	°C
Ts						
to tf	Innut Disc and Fall Time	Control Input $VCC = 2.3V$ to $3.6V$	0	-	10	ns/V
tr, tf	Input Rise and Fall Time	Control Input $V_{CC} = 4.5V$ to $5.5V$	0	-	5	ns/V

Note: Control input must be held HIGH or LOW; it must not float.







DC Electrical Characteristics ($T_A = -40$ °C to 85 °C, unless otherwise noted.)

Parameter	Description	Test Conditions	Temperature (T _A : °C)	Min.	Тур.	Max.	Units
V_{IAR}	Analog Input Signal Range	V _{CC}	-40°C to 85°C	0	1	V_{CC}	V
		V_{CC} =4.5V, I_{O} = 30mA, V_{IN} = 0V		-	4	6	
		V_{CC} =4.5V, I_{O} =-30mA, V_{IN} =2.4V	25°C	-	5	8	
		V_{CC} =4.5V, I_{O} =-30mA, V_{IN} =4.5V		-	7	11	
		$V_{CC}=4.5V, I_{O}=30mA, V_{IN}=0V$		-	-	6	
		V_{CC} =4.5V, I_{O} =-30mA, V_{IN} =2.4V	-40°C to 85°C	-	-	8	
		V_{CC} =4.5V, I_{O} =-30mA, V_{IN} =4.5V		-	-	11	
		V_{CC} =3.0V, I_{O} =24mA, V_{IN} =0V	25°C	-	5	8	
		V_{CC} =3.0V, I_{O} =-24mA, V_{IN} =3.0V		-	10	15	
R_{ON}	ON Resistance ⁽¹⁾	$V_{CC} = 3.0 \text{V}, I_O = 24 \text{mA}, V_{IN} = 0 \text{V}$	-40°C to 85°C	-	-	8	Ω
011		$V_{CC} = 3.0 \text{V}, I_{O} = -24 \text{mA}, V_{IN} = 3.0 \text{V}$		-	-	15	
		$V_{CC}=2.3V$, $I_O=8mA$, $V_{IN}=0V$	25°C	-	6	9	
		$V_{CC}=2.3V, I_{O}=-8mA, V_{IN}=2.3V$		-	13	20	
		$V_{CC}=2.3V$, $I_O=8mA$, $V_{IN}=0V$	-40°C to 85°C	-	-	9	
		$V_{CC}=2.3V$, $I_{O}=-8mA$, $V_{IN}=2.3V$		-	- 0	20 12	
		$V_{CC}=1.65V, I_{O}=4mA, V_{IN}=0V$	25°C	-	8 20	30	
		$V_{CC}=1.65V$, $I_{O}=-4mA$, $V_{IN}=1.65V$		-		12	
		V_{CC} =1.65V, I_{O} =4mA, V_{IN} =0V	-40°C to 85°C	_	-	25	
		V_{CC} =1.65V, I_{O} =-4mA, V_{IN} =1.65V		-	0.15		
	ON Resistance	V_{CC} =4.5V, I_A =-30mA, V_{IN} =3.15V V_{CC} =3.0V, I_A =-24mA, V_{IN} =2.1V	25°C	-	0.13	-	Ω
ΔR_{ON}	Match Between	$V_{CC}=2.3V$, $I_A=-24mA$, $V_{IN}=2.1V$ $V_{CC}=2.3V$, $I_A=-8mA$, $V_{IN}=1.6V$			0.2	-	
	Channels ^(1,2,3)	$V_{CC}=1.65V, I_A=-6mA, V_{IN}=1.6V$ $V_{CC}=1.65V, I_A=-4mA, V_{IN}=0V$		_	0.5	-	
		$V_{CC}=5.0V, I_A=-30mA,$		_	0.5	_	
		$0 \le V_{IN} \le V_{CC}$	25°C	-	6	-	Ω
R_{ONF}	ON Resistance	$V_{CC}=3.3V$, $I_A=-24mA$, $0 \le V_{IN} \le V_{CC}$		-	12	-	
TONF	Flatness ^(1,2,4)	V_{CC} =2.5V, I_A =-8mA, $0 \le V_{IN} \le V_{CC}$		-	22	-	
		$V_{CC}=1.8V$, $I_A=-4$ mA, $0 \le V_{IN} \le V_{CC}$	-	-	90	-	
		$V_{\rm CC}=1.65$ V		1	-	-	
	* ***	$V_{CC} = 2.3V$		1.2	-	-	
V_{IH}	Input High Voltage	$V_{CC} = 3V$	-40°C to 85°C	1.3	-	-	V
	(Logic High Level)	$V_{\rm CC} = 4.2 \text{V}$		1.5	-	-	
		$V_{CC} = 5.5V$		1.8	-	-	
		V _{CC} =1.65V		-	-	0.4	
	Input Low Voltage	$V_{CC} = 2.3V$		-	ı	0.6	
V_{IL}	(Logic Low Level)	$V_{CC} = 3V$	-40°C to 85°C	-	ı	0.8	V
((Logic Low Level)	$V_{CC} = 4.2V$		-	-	1	
		$V_{CC} = 5.5V$		-	-	1.2	
I_{LKC}	Input Leakage	$0 \le V_{IN} \le 5.5 \text{ V}, V_{CC} = 0 \text{ V to } 5.5 \text{ V}$	25°C	-	-	±0.1	μA
-LKC	Current	- TIN_5.5 T, TCC=5 T to 5.5 T	-40°C to 85°C	-	-	±1.0	μ11
I_{OFF}	OFF State Leakage	$0 \le V_{IN} \le 5.5 \text{ V}, V_{CC} = 1.65 \text{ V} \text{ to } 5.5 \text{ V}$	25°C	-	-	±0.1	μA
-OrF	Current		-40°C to 85°C	-	-	±10	ļ
I_{CC}	Quiescent Supply	All channels ON or OFF, $V_{IN} = V_{CC}$	25°C	-	-	1	μΑ
CC	Current	or GND, $I_{OUT}=0$, $V_{CC}=5.5V$	-40°C to 85°C	-	-	5	F -

Notes:

^{1.} Measured by voltage drop between A and B pins at the indicated current through the device. ON resistance is determined by the lower of the voltages on two ports (A or B).

^{2.} Parameter is characterized but not tested in production.

^{3.} $DR_{ON} = R_{ON} \text{ max} - R_{ON} \text{ min.}$ measured at identical V_{CC} , temperature and voltage levels.

^{4.} Flatness is defined as difference between maximum and minimum value of ON resistance over the specified range of conditions. Guaranteed by design.





Capacitance⁽¹⁾($T_A = 25$ °C, unless otherwise noted.)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
C_{IN}	Control Input		-	2.5	-	
$C_{\text{IO-B}}$	For B Port, Switch OFF	(1)	-	5.0	-	_
C _{IOA-ON}	For A Port, Switch ON	$V_{CC} = 5.0V$, f = 1 MHz	-	15.0	-	pF

Notes:

Switch and AC Characteristics(1)

Parameter	Description	Test Conditions	Supply Voltage	Temperature (T _A : °C)	Min	Тур	Max	Units
	t _{p1H} Propagation	1 (2)	$V_{CC} = 1.65 \text{V} \text{ to } 1.95 \text{V}$	-40 to 85°C	-	-	3.5	
t PLH			$V_{\rm CC} = 2.3 \text{V to } 2.7 \text{V}$		-	-	1.1	
t_{PHL}	Delay: A to Bn		$V_{CC} = 3.0 \text{V to } 3.6 \text{V}$		-	-	0.9	
			$V_{CC} = 4.5 \text{V to } 5.5 \text{V}$		-	-	0.6	
		See test circuit diagrams	$V_{CC} = 1.65 \text{V} \text{ to } 1.95 \text{V}$		6	-	13	
t _{PZL}	Output Enable	1&2.	$V_{CC} = 2.3V \text{ to } 2.7V$	40 4 0500	3.5	-	8.0	
t_{PZH}	Turn ON Time: A to Bn	$V_I = 2V_{CC}$ for t_{PZL} ,	$V_{CC} = 3.0 \text{V to } 3.6 \text{V}$	-40 to 85°C	2.5	-	6.9	- -
		$V_I = 0V$ for t_{PZH}	$V_{\rm CC} = 4.5 \text{V to } 5.5 \text{V}$		1.7	-	5.2	
		See test circuit diagrams 1	$V_{CC} = 1.65 \text{V} \text{ to } 1.95 \text{V}$		3	-	13	ns
${ m t}_{{ m PL}Z}$	Output Disable Turn	n and 2.	$V_{CC} = 2.3 \text{V to } 2.7 \text{V}$	-40 to 85°C	2	-	9	
t_{PHZ}	OFF Time:A to Bn		$V_{CC} = 3.0 \text{V to } 3.6 \text{V}$		1.5	-	7.0	
			$V_{CC} = 4.5 \text{V to } 5.5 \text{V}$		0.8	-	4.5	
		See test circuit diagram 3	$V_{CC} = 1.65 \text{V} \text{ to } 1.95 \text{V}$	−40 to 85°C	-	3.7	-	
Break Befo	Break Before		$V_{CC} = 2.3V \text{ to } 2.7V$		-	2.5	-	
$t_{_{ m BM}}$	Make Time		$V_{CC} = 3.0 \text{V} \text{ to } 3.6 \text{V}$		-	2.5	-	
			$V_{CC} = 4.5 \text{V to } 5.5 \text{V}$		-	1.6	-	
Q	Charge	$C_{L} = 0.1 \text{nF}, V_{GEN} = 0 \text{V},$	$V_{CC} = 5.0V$	25℃	-	5	-	pC
Q	Injection	$R_{GEN} = 0\Omega$. See test circuit 4.	$V_{CC} = 3.3V$	25 C	-	4	-	pc
OIRR	Off Isolation	R_L =50 Ω , V_{GEN} =0 V , R_{GEN} =0 Ω , f =10 M Hz. See test circuit 5	$V_{CC} = 1.65 \text{V} \text{ to } 5.5 \text{V}$	25℃	-	-63	-	dB
X_{TALK}	Crosstalk Isolation	See test circuit 6 (4)	$V_{CC} = 1.65 \text{V to } 5.5 \text{V}$	25℃	-	-64	-	
f3dB	-3dB Bandwidth	See test circuit 9	$V_{\rm CC} = 1.65 \text{V to } 5.5 \text{V}$	25℃	-	350	-	MHz
T_{HD}	Total Harmonic Distortion	R_L =600 Ω , V_{IN} =0.5 V pp, f =20 Hz to 20 k Hz	$V_{CC} = 1.65 \text{V to } 5.5 \text{V}$	25°C	-	0.012	-	%

Notes:

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^{1.} Capacitance is characterized but not tested in production

^{1.} Guaranteed by design.

^{2.} The device contributes no other propagation delay other than the RC delay of the switch ON resistance and the 50pF load capacitance, when driven by an ideal voltage source with zero output impedance.

^{3.} Off Isolation = 20 Log_{10} [V_{Bn}/V_A] and is measured in dB.

^{4.} Crosstalk Isolation = $20 Log_{10}$ [V_{B1}/V_{B0}] and is measured in dB.



Test Circuits and Timing Diagrams

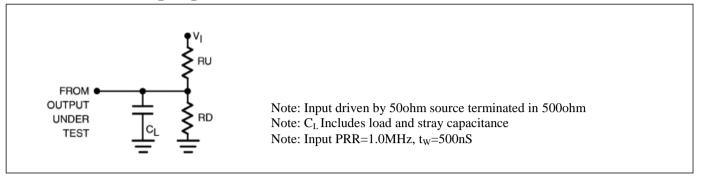


Figure 1. AC Test Circuit

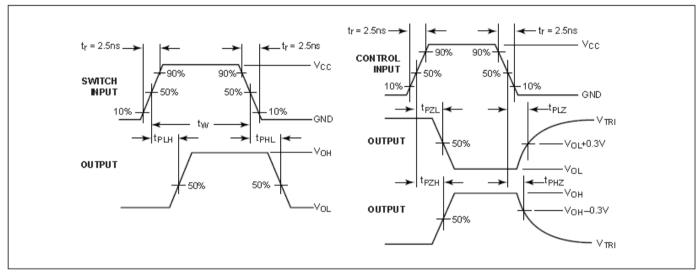


Figure 2. AC Waveforms

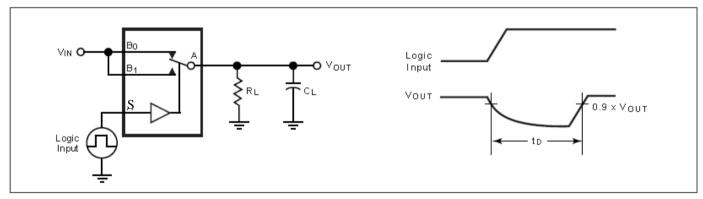


Figure 3. Break Before Make Interval Timing



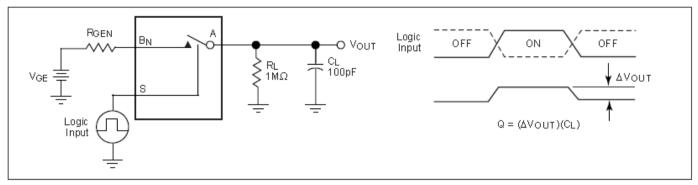
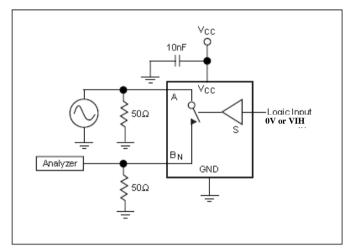


Figure 4. Charge Injection Test



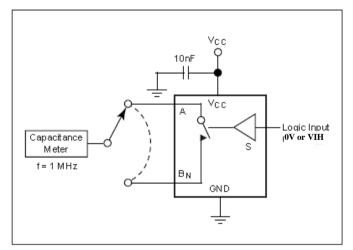
Signal Generator OdBm

Analyzer

Son

Figure 5. Off Isolation

Figure 6. Crosstalk





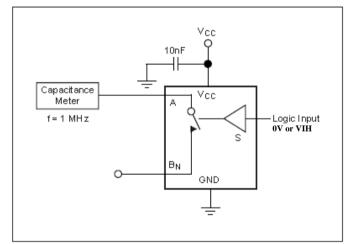


Figure 8. Channel On Capacitance



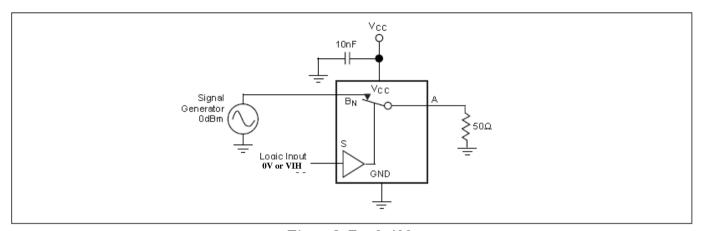
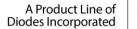


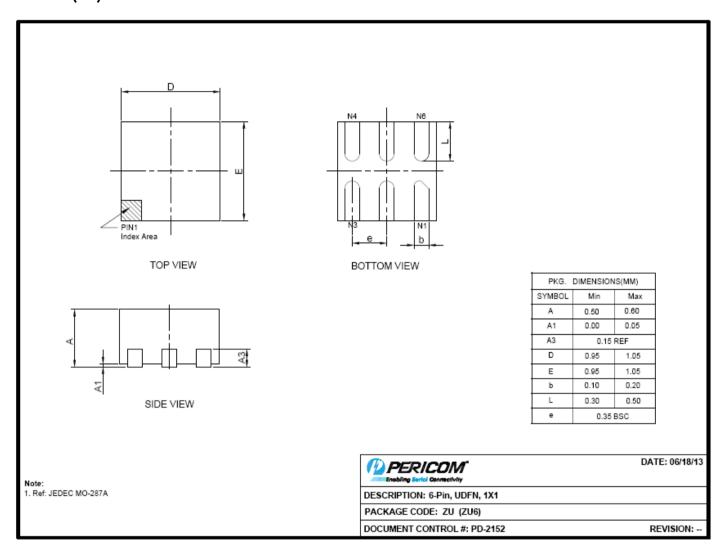
Figure 9. Bandwidth



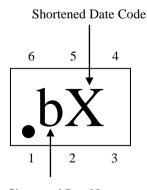




Mechanical Information: 6-UDFN (ZU)

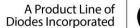


Marking Description



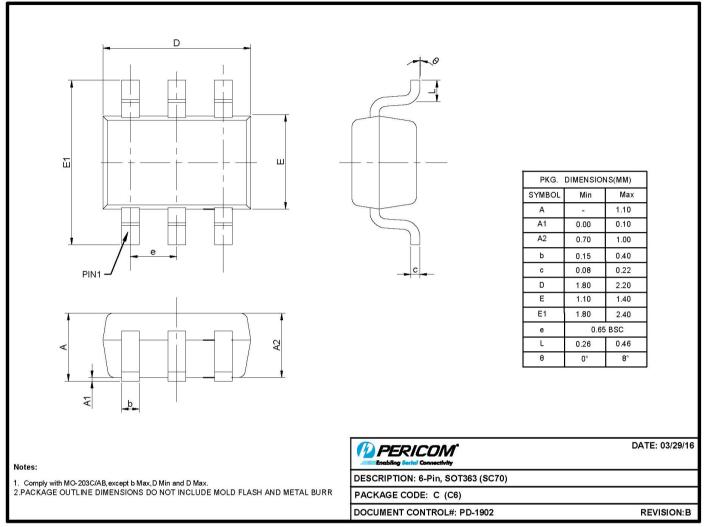
Shortened Part No







6-SC70 (C6)



16-0078

For latest package info.

please check: http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/

Ordering Information

Part Number	Package Code	Package	Top Marking
PI5A3157BZUEX	ZU	6-Pin, 1x1 (UDFN)	b
PI5A3157BC6EX	C6	6-Pin, SOT363 (SC70)	kD

Notes:

- Thermal characteristics can be found on the company web site at www.diodes.com/design/support/packaging/
- E = Pb-free and Green
- X suffix = Tape/Reel





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